

^{捷多邦}N寿46°铅杠样TN7594、时和象出货 1N4370 thru 1N4372A, -1 DO-35

Silicon 500 mW Zener Diodes

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IMPORTANT: For the most current data, consult *MICROSEMI's* website: <u>http://www.microsemi.com</u>

Microsemi also offers numerous other Zener

DESCRIPTION

The popular 1N746 thru 1N759A and 1N4370 thru 1N4372A series of 0.5

watt Zener Voltage Regulators provides a selection from 2.4 to 12 volts in

standard 5% or 10% tolerances as well as tighter tolerances identified by different suffix letters on the part number. These glass axial-leaded DO-35 Zeners are also available with an internal-metallurgical-bond option by adding a "-1" suffix. These are also available in JAN, JANTX, and JANTXV

FEATURES

products to meet higher and lower power applications.

military qualifications.

- JEDEC registered 1N746 thru 1N759A and 1N4370 thru 1N4372A series
- Internal metallurgical bond option available by adding a "-1" suffix
- Also available in JAN, JANTX, and JANTXV qualifications per MIL-PRF-19500/127 by adding the JAN, JANTX, or JANTXV prefixes to part numbers for desired level of screening as well as –1" suffix; (e.g. JANTX1N751A-1, JANTXV1N758C-1, etc.)
- Military Surface Mount equivalents also available in DO-213AA by adding a UR-1 suffix in addition to the JAN, JANTX, and JANTXV prefix; e.g. JANTX1N962BUR-1 (see separate data sheet)
- Commercial Surface Mount equivalents available as MLL746 to MLL759A and MLL4370 to MLL4372A including the "-1" suffix in the DO-213AA MELF style package (consult factory for others)
- DO-7 glass body axial-leaded Zener equivalents are also available

MAXIMUM RATINGS

- Operating and Storage temperature: -65°C to +175°C
- Thermal Resistance: 250 °C/W junction to lead at 3/8 (10 mm) lead length from body, or 310 °C/W junction to ambient when mounted on FR4 PC board (1 oz Cu) with 4 mm² copper pads and track width 1 mm, length 25 mm
- Steady-State Power: 0.5 watts at T_L ≤ 50°C 3/8 inch (10 mm) from body or 0.48 W at T_A ≤ 25°C when mounted on FR4 PC board as described for thermal resistance above (also see Figure1)
- Forward voltage @200 mA: 1.1 volts
- Solder Temperatures: 260 °C for 10 s (max)

APPLICATIONS / BENEFITS

DO-35

(DO-204AH)

APPEARANCE

- Regulates voltage over a broad operating
 current and temperature range
- Selection from 2.4 to 12 V
- Standard voltage tolerances are plus/minus 5% with A suffix identification and 10 % with no suffix
- Tight tolerances available in plus or minus 2% or 1% with C or D suffix respectively
- Flexible axial-lead mounting terminals
- Nonsensitive to ESD per MIL-STD-750 Method
 1020
- Minimal capacitance (see Figure 3)
- Inherently radiation hard as described in Microsemi MicroNote 050

MECHANICAL AND PACKAGING

- CASE: Hermetically sealed axial-lead glass
 DO-35 (DO-204AH) package
- TERMINALS: Leads, tin-lead plated solderable per MIL-STD-750, method 2026
- POLARITY: Cathode indicated by band. Diode to be operated with the banded end positive with respect to the opposite end for Zener regulation
- MARKING: Part number
- TAPE & REEL option: Standard per EIA-296 (add "TR" suffix to part number)
- WEIGHT: 0.2 grams
- See package dimensions on last page

1N746 –759A 1N4370 – 4372A (DO-35)



Microsemi

1N746 thru 1N759A, -1 and 1N4370 thru 1N4372A, -1 DO-35

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	ELECTRICAL CHARACTERISTICS* @ 25°C								
	JEDEC YPE NO.	NOMINAL ZENER VOLTAGE	ZENER TEST CURRENT	MAXIMUM ZENER IMPEDANCE	MAXIMUM REVERSE CURRENT I _R @ V _R = 1 VOLT		MAXIMUM ZENER CURRENT	TYPICAL TEMP COEFF. OF ZENER	
()	NOTE1)	V _Z @ I _{ZT} (NOTE 2)	I _{ZT}	Z _{ZT} @ I _{ZT} (NOTE 3)	@25°C	@+150°C	I _{ZM} (NOTE 4)	VOLTAGE αvz	
		VOLTS	mA	OHMS	μΑ	μ Α	mA	%/°C	
1N4	4370	2.4	20	30	100	200	150	085	
1N4	4371	2.7	20	30	75	150	135	080	
1N4	4372	3.0	20	29	50	100	120	075	
1N7	746	3.3	20	28	10	30	110	066	
1N7	747	3.6	20	24	10	30	100	058	
1N7	748	3.9	20	23	10	30	95	046	
1N7	749	4.3	20	22	2	30	85	033	
1N7	750	4.7	20	19	2	30	75	015	
1N7	751	5.1	20	17	1	20	70	+/010	
1N7	752	5.6	20	11	1	20	65	+.030	
1N7	753	6.2	20	7	.1	20	60	+.049	
1N7	754	6.8	20	5	.1	20	55	+.053	
1N7	755	7.5	20	6	.1	20	50	+.057	
1N	756	8.2	20	8	.1	20	45	+.060	
1N7	757	9.1	20	10	.1	20	40	+.061	
1N7		10.0	20	17	.1	20	35	+.062	
1N7	759	12.0	20	30	.1	20	30	+.062	

* JEDEC Registered Data

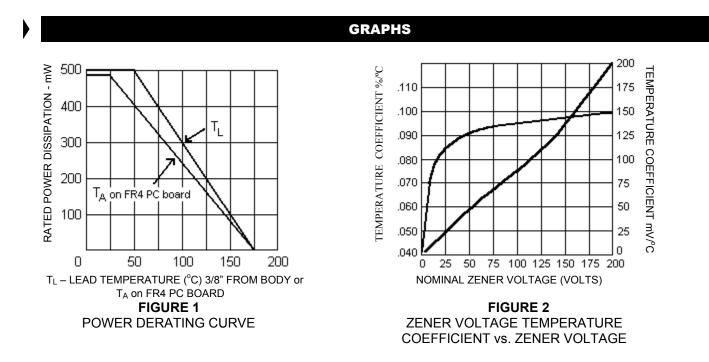
NOTE 1: Standard tolerance on JEDEC types shown is +/- 10%. Suffix letter A denotes +/- 5% tolerance; suffix

letter C denotes +/- 2%; and suffix letter D denotes +/- 1% tolerance.

NOTE 2: Voltage measurements to be performed 20 seconds after application of dc test current.

NOTE 3: Zener impedance derived by superimposing on I_{ZT}, a 60 cps, rms ac current equal to 10% I_{ZT} (2mA ac). See MicroNote 202 for typical zener Impedance variation with different operating currents.

NOTE 4: Allowance has been made for the increase in V_z due to Z_z and for the increase in junction temperature as the unit approaches thermal equilibrium at the power dissipation of 400 mW.



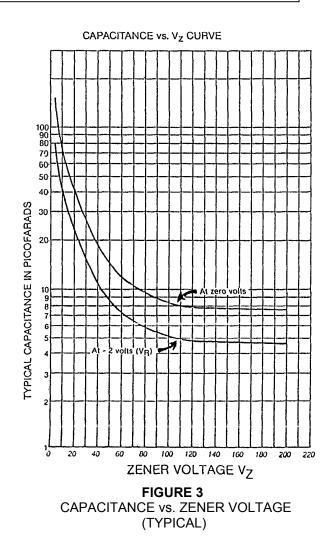
1N4370 – 4372A (DO-35)

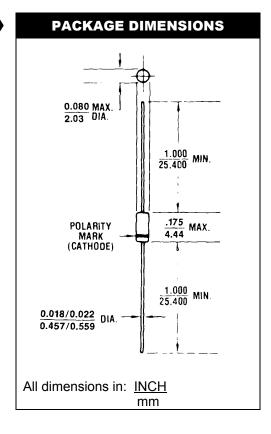
1N746 –759A



1N746 thru 1N759A, -1 and 1N4370 thru 1N4372A, -1 DO-35

Silicon 500 mW Zener Diodes





1N746 –759A 1N4370 – 4372A (DO-35) This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.